XP840

Study of the correlation between GAE activity and electron transport

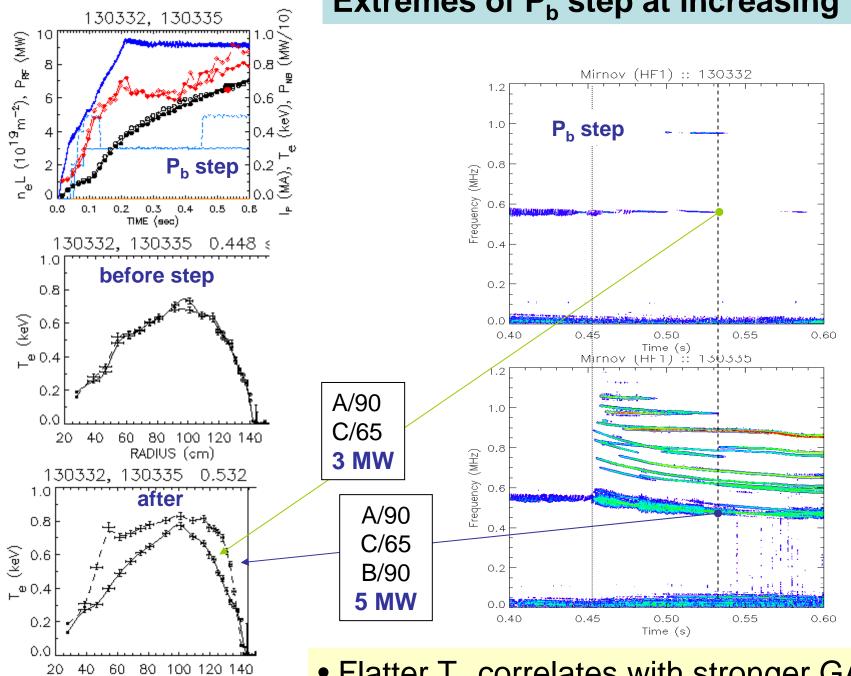
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Goals

- Compare T_e in plasmas with/without GAEs (few scenarios)
- Same q, n_e as much as possible
- Document with high-k (GAEs, turbulence), neon injection
- Scenario I: P_b step at fixed-q and increasing V_b (two fields)
- good results at 4.5 kG: T_e flattening correlates with GAE increase
- good GAE data with high-k interferometry; not much scattering (ETGs)
- good data also at 5.5 kG, but H-mode late (q changed)
- neon injection collapsed discharge (post-Li?); high n_e, metals
- Scenario II: Compare plasmas with same P_b but different V_b
- achieved low V_b /high V_b 4 MW H-modes
- not striking difference in GAE activity
- possibly better electron transport with less GAEs
- Scenario III: Compare RF heating in NB deuterium plasma with/w.o. GAEs

Extremes of P_b step at increasing V_b



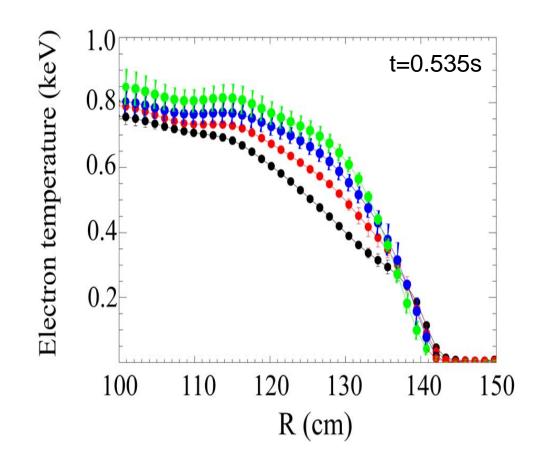
130332, 130335

RADIUS (cm)

Flatter T_e correlates with stronger GAEs

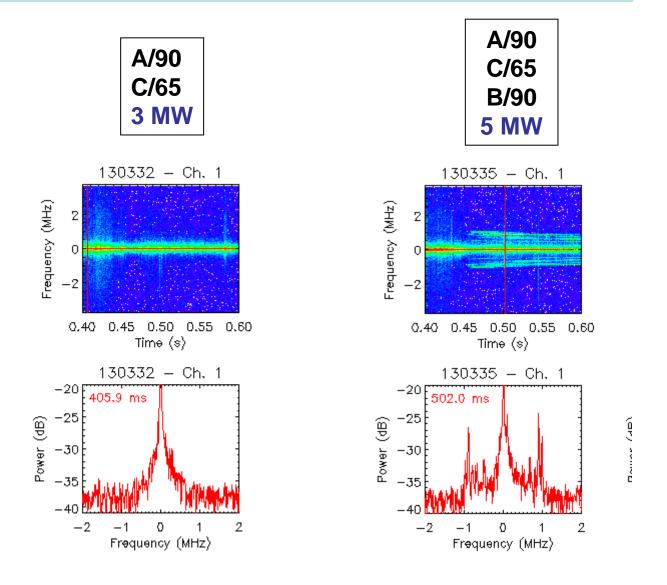
V_b scan confirms progressive flattening





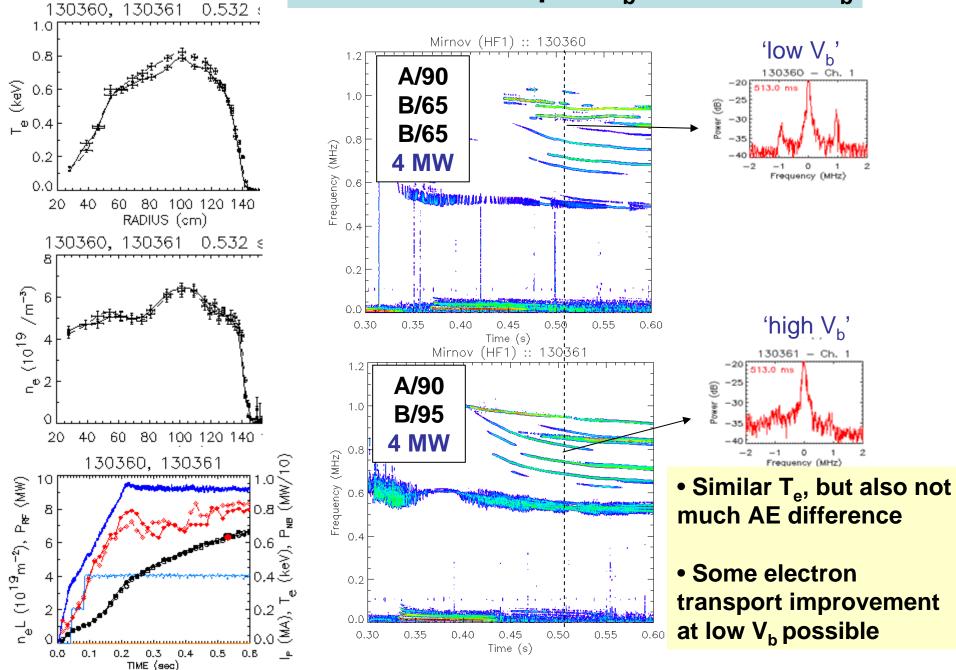
T_e averaged between t=0.51-0.54 s

High-k interferometric data for GAE amplitude

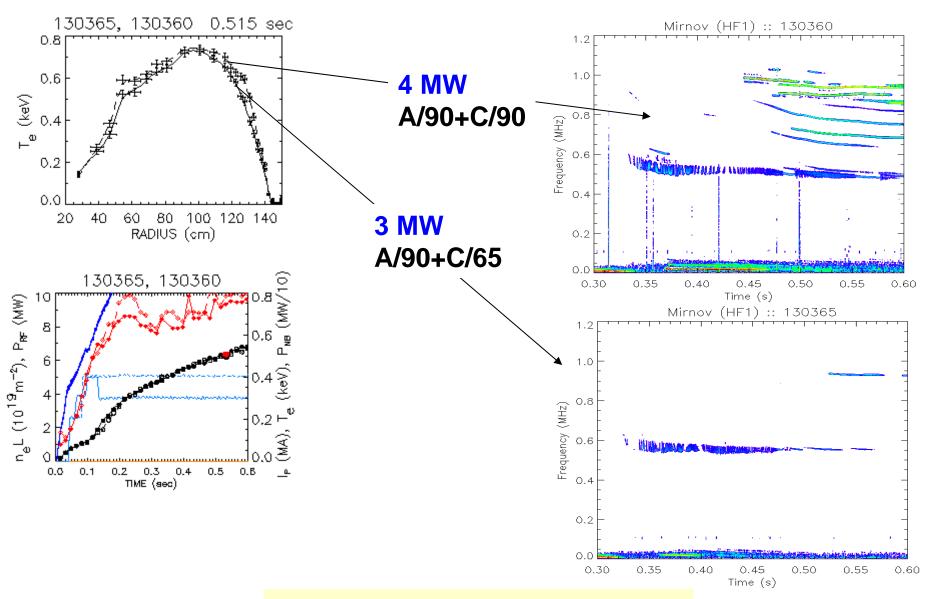


Not much high-k scattering

Plasmas with equal P_b at different V_b



At low V_b plasma with less P_b has similar T_e



Overall encouraging results